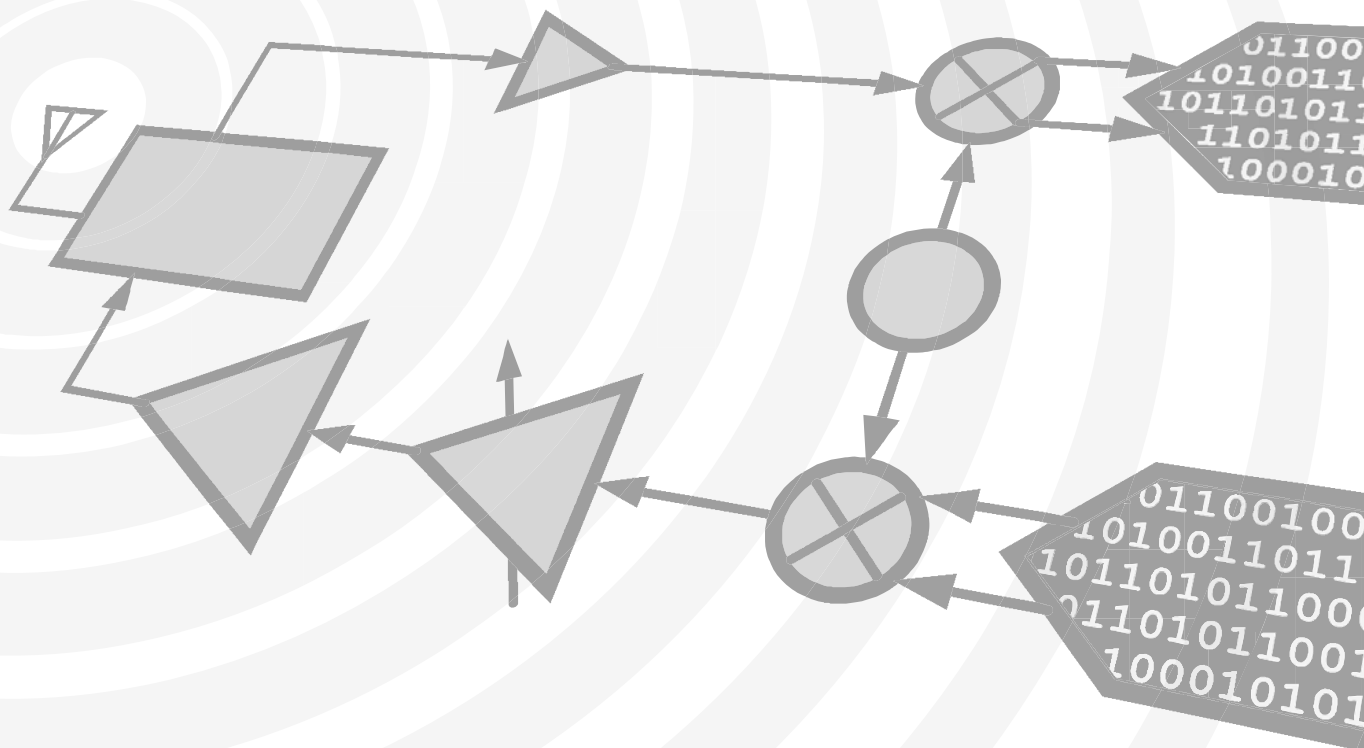


Analog Devices Welcomes Hittite Microwave Corporation

NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



HMC549* Product Page Quick Links

Last Content Update: 11/01/2016

Comparable Parts

View a parametric search of comparable parts

Evaluation Kits

- HMC549MS8G Evaluation Board

Documentation

Application Notes

- AN-1363: Meeting Biasing Requirements of Externally Biased RF/Microwave Amplifiers with Active Bias Controllers
- Broadband Biasing of Amplifiers General Application Note
- MMIC Amplifier Biasing Procedure Application Note
- Thermal Management for Surface Mount Components General Application Note

Data Sheet

- HMC549 Data Sheet

Reference Materials

Quality Documentation

- HMC Legacy PCN: MS##, MS##E and MS##G,MS##GE packages - Relocation of pre-existing production equipment to new building
- Package/Assembly Qualification Test Report: MS8G (QTR: 2014-00393)
- PCN: MS, QS, SOT, SOIC packages - Sn/Pb plating vendor change
- Semiconductor Qualification Test Report: PHEMT-B (QTR: 2013-00233)

Design Resources

- HMC549 Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

Discussions

View all HMC549 EngineerZone Discussions

Sample and Buy

Visit the product page to see pricing options

Technical Support

Submit a technical question or find your regional support number

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MICROWAVE CORPORATION

v02.0310



HMC549MS8G / 549MS8GE

DUAL OUTPUT LOW NOISE AMPLIFIER, 0.04 - 0.96 GHz

Typical Applications

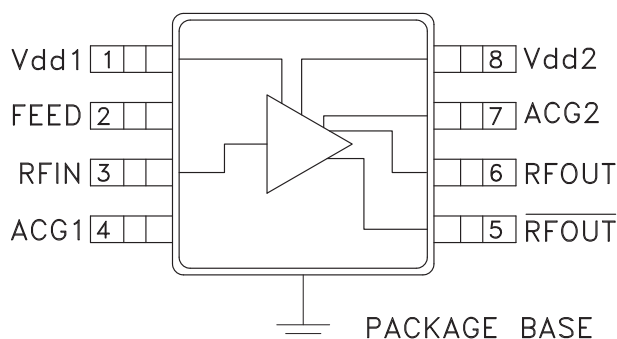
The HMC549MS8G(E) is ideal for:

- DTV Receivers
- Multi-Tuner Set Top Boxes
- PVRs & Home Gateways

Features

- Single-ended or Balanced Output
- High Output IP3: +27 dBm
- Low Noise Figure: 3.5 dB
- Single Positive Supply: +5V
- 75 Ohm Input

Functional Diagram



General Description

The HMC549MS8G(E) is a GaAs PHEMT MMIC Low Noise Amplifier that are ideal pre-amplifiers for CATV Set Top Box, Home Gateway, and Digital Television receiver operating between 40 and 960 MHz. This high dynamic range LNA has been optimized to provide 3.5 dB noise figure and +27 dBm output IP3 from a single supply of +5V @ 120 mA. The outputs of this LNA are extremely well balanced, and can be used to drive a differential input tuner with very high input IP2 requirements. This dual purpose LNA can also be used as an active splitter driving two single-ended input tuners. This LNA is housed in a RoHS compliant MSOP8G SMT package with exposed ground paddle.

Electrical Specifications, 75 Ohm System, $T_A = +25^\circ\text{C}$, $V_{dd} = +5\text{V}$

Parameter*	Min.	Typ.	Max.	Units
Frequency Range	0.04 - 0.96			GHz
Gain	2	5		dB
Gain Variation over Temperature		0.01	0.02	dB/°C
Noise Figure		3.5	5.2	dB
Input Return Loss		8		dB
Output Return Loss		15		dB
Output Power for 1 dB Compression (P1dB)		12.5		dBm
Output Third Order Intercept (OIP3)		27		dBm
Output Second Order Intercept (OIP2)		52		dBm
Amplitude Balance		0.3		dB
Phase Balance		2		deg
Supply Current (Idd)		120		mA

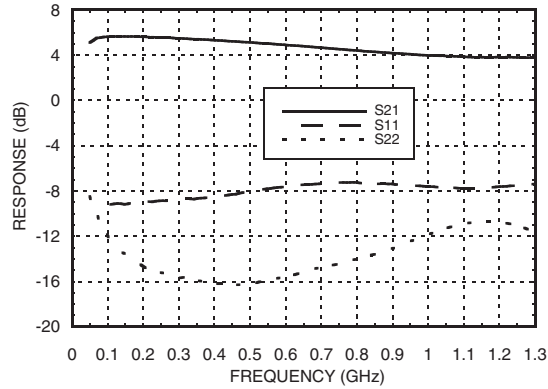
* Unless otherwise noted, all measurements performed with balun on the output.

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

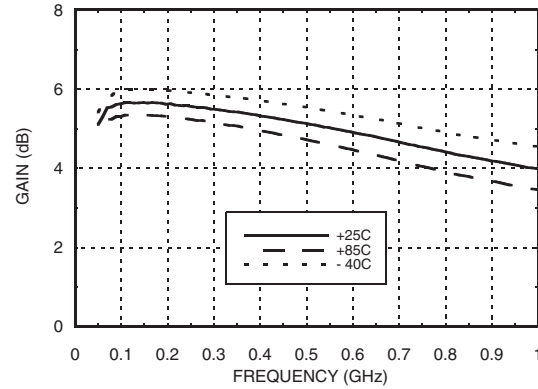
Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

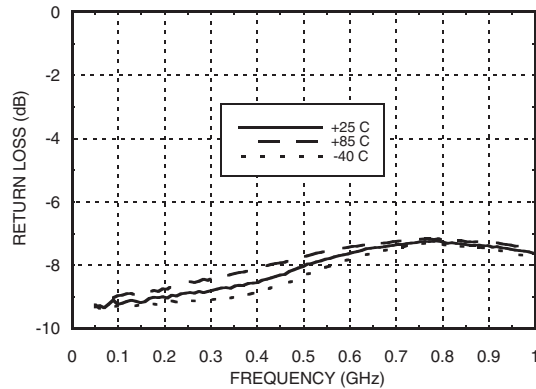
Broadband Gain & Return Loss



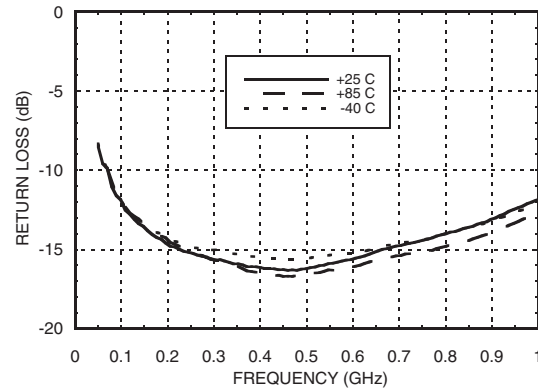
Gain vs. Temperature



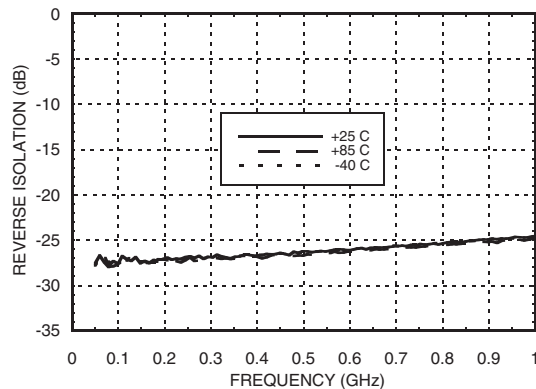
Input Return Loss vs. Temperature



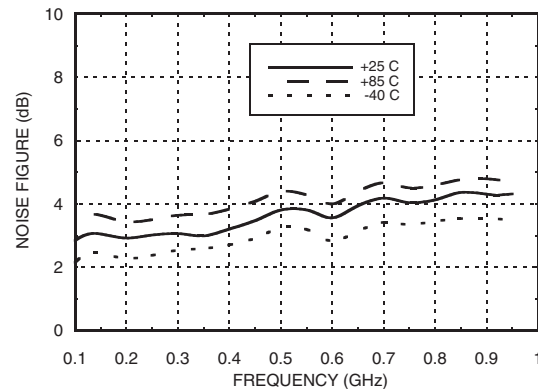
Output Return Loss vs. Temperature



Reverse Isolation vs. Temperature

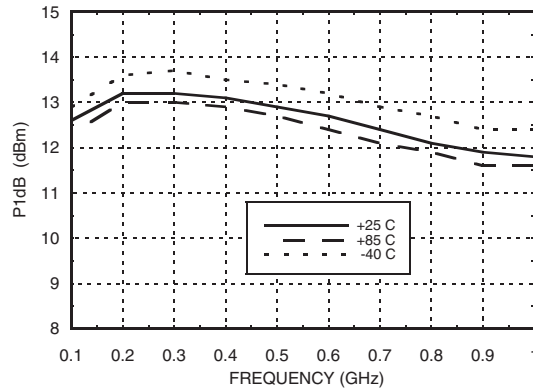


Noise Figure vs. Temperature

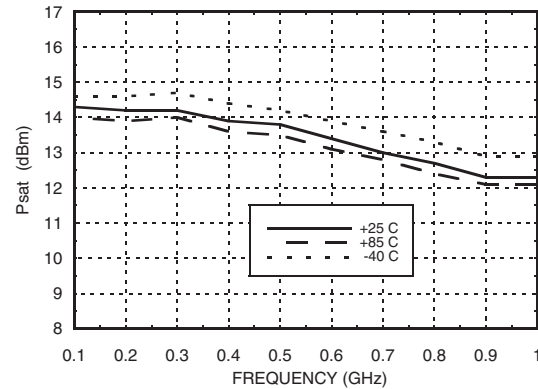


All measurements taken in 75 Ohm system.

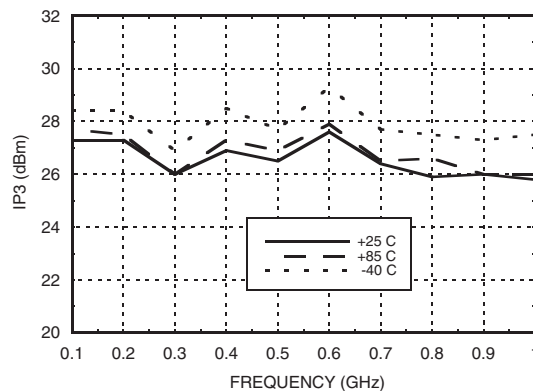
P1dB vs. Temperature



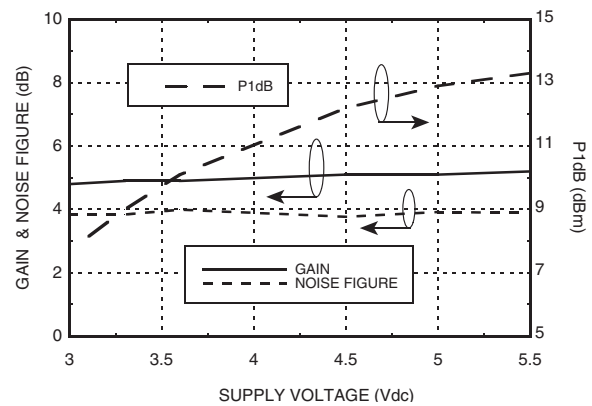
Psat vs. Temperature



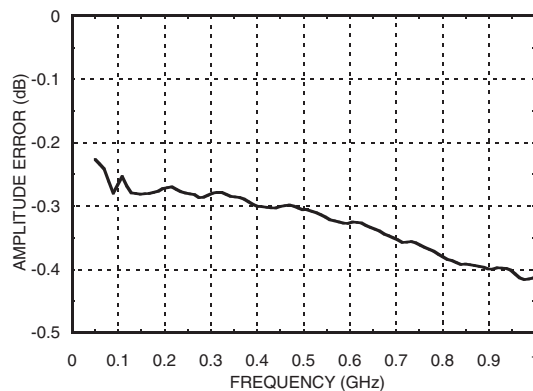
Output IP3 vs. Temperature



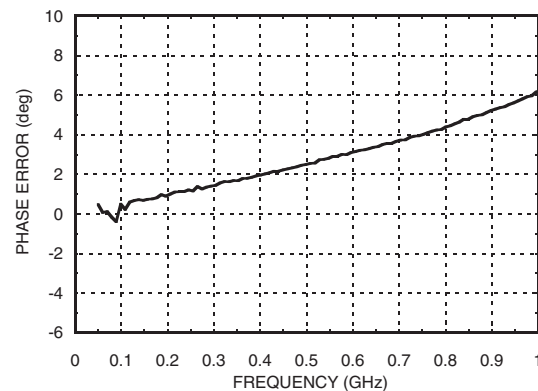
**Gain, Noise Figure & P1dB vs.
Supply Voltage @ 500 MHz**



Amplitude Balance *



Phase Balance *



* Data taken without balun on the output.

All measurements taken in 75 Ohm system.

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824

Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

Application Support: Phone: 978-250-3343 or apps@hittite.com

Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+7V
RF Input Power (RFIN)(Vdd = +3 Vdc)	0 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 20 mW/°C above 85 °C)	1.32 W
Thermal Resistance (channel to ground paddle)	49 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

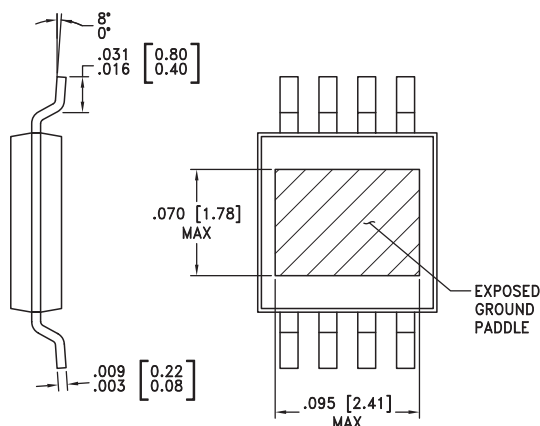
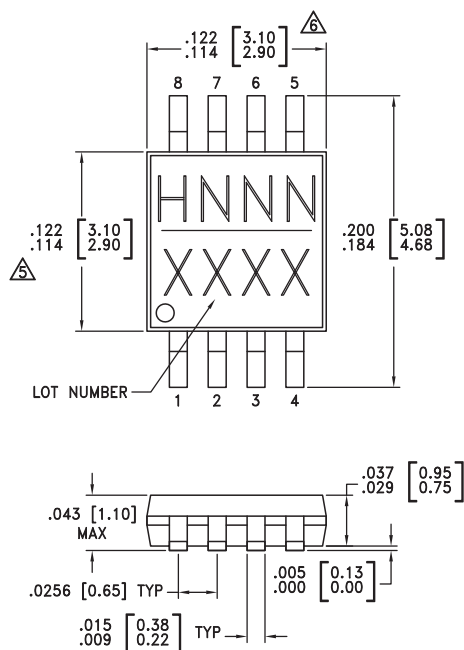
Typical Supply Current vs. Vdd

Vdd (Vdc)	Idd (mA)
3.0	117.1
3.3	117.5
3.6	117.9
4.5	118.5
5.0	119.0
5.5	119.3



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



NOTES:

1. PACKAGE BODY MATERIAL: LOW STRESS INJECTION MOLDED PLASTIC. SILICA AND SILICON IMPREGNATED.
2. LEAD AND GROUND PADDLE MATERIAL: COPPER ALLOY
3. LEAD AND GROUND PADDLE PLATING: 100% MATTE TIN.
4. DIMENSIONS ARE IN INCHES [MILLIMETERS]
5. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.15mm PER SIDE.
6. DIMENSION DOES NOT INCLUDE MOLDFLASH OF 0.25mm PER SIDE.
7. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

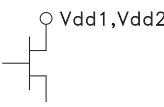
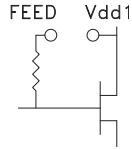
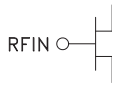
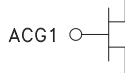
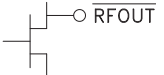
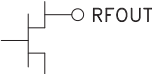
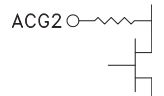
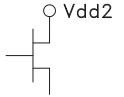
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC549MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H549 XXXX
HMC549MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	H549 XXXX

[1] Max peak reflow temperature of 235 °C

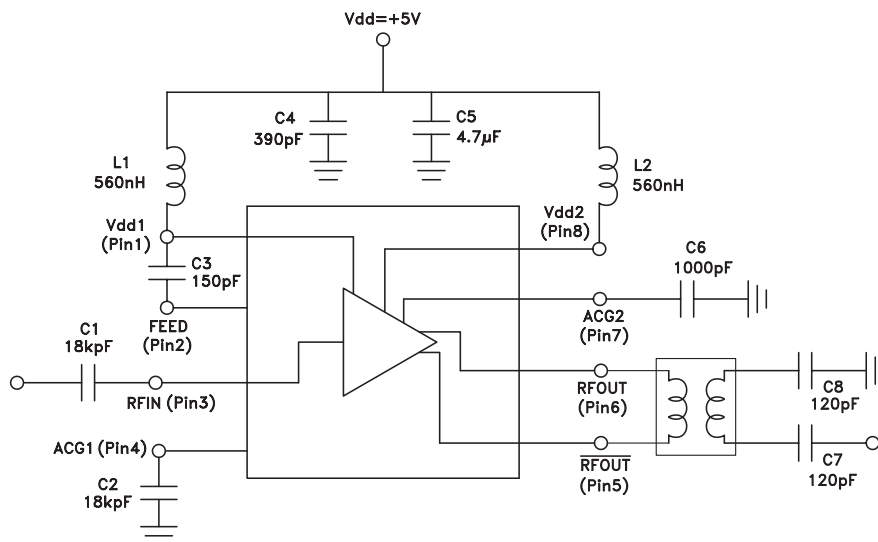
[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

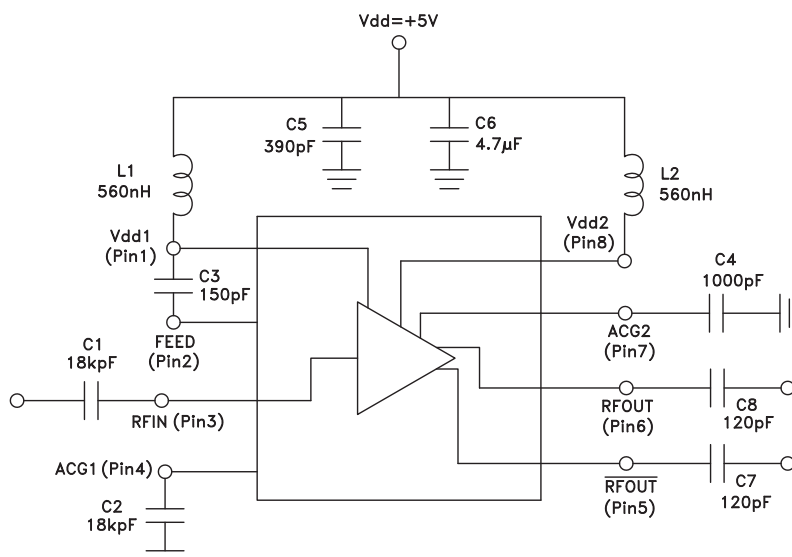
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1, 8	Vdd1, Vdd2	Power supply voltage for the first stage. An external choke inductor is required. See application circuit.	
2	FEED	Feedback capacitor for the first stage.	
3	RFIN	This pin is DC coupled and requires a DC blocking cap. See application circuit.	
4	ACG1	This pin has to be terminated by an external capacitor. See application circuit.	
5	$\overline{\text{RFOUT}}$	RF differential output 2. This port is DC coupled.	
6	RFOUT	RF differential output 1. This port is DC coupled.	
7	ACG2	This pin has to be terminated by an external capacitor. See application circuit.	
8	Vdd2	Power supply voltage for second stage. An external choke inductor is required. See application circuit.	

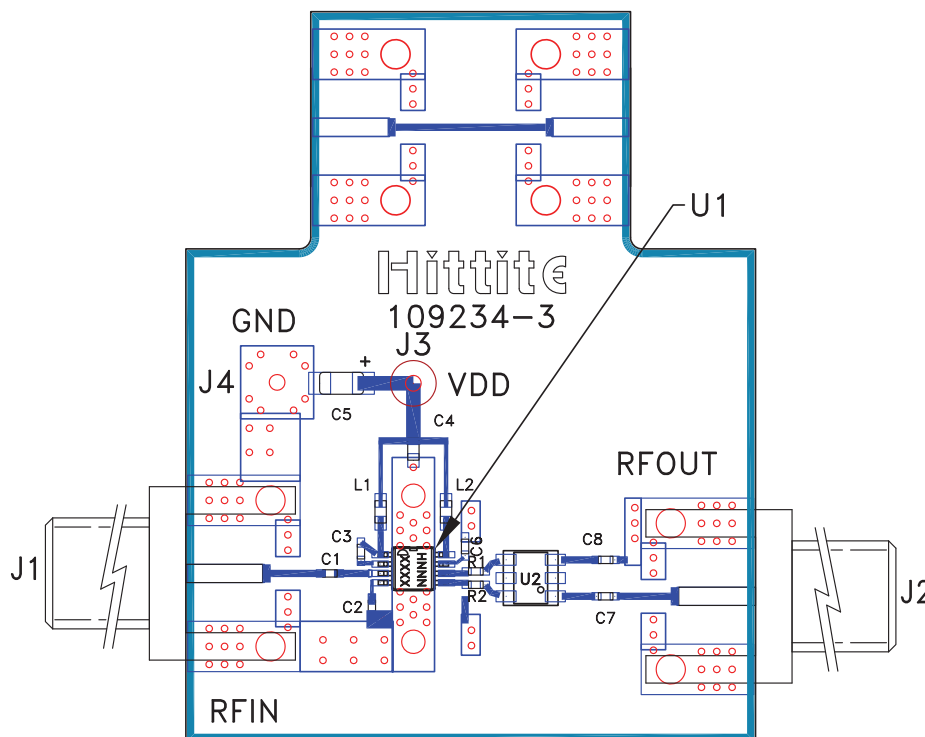
Application Circuit for 109236 - HMC549MS8G(E) (2-port)



Application Circuit for 113184 - HMC549MS8G(E) (3-port)



Evaluation PCB



List of Materials for Evaluation PCB 109236 ^[1]

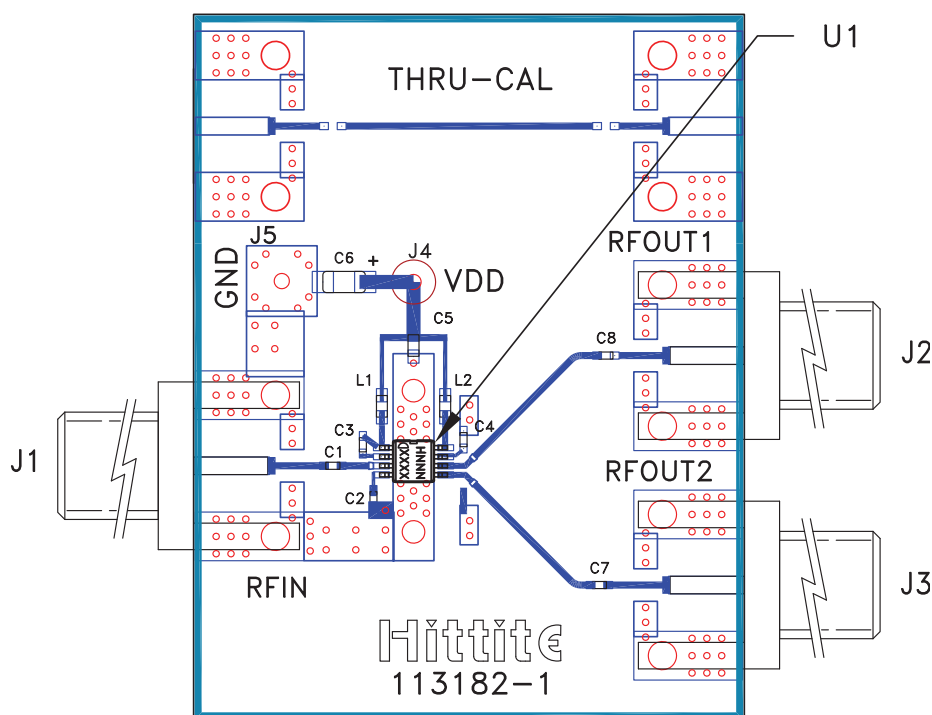
Item	Description
J1, J2	BOMAR F Type 75 Ohm Connectors
J3, J4	DC Pin
C1, C2	18 k Ω Capacitor, 0402 Pkg.
C3	150 pF Capacitor, 0402 Pkg.
C4	390 pF Capacitor, 0603 Pkg.
C5	4.7 μ F Capacitor, Tantalum
C6	1,000 pF Capacitor, 0402 Pkg.
C7, C8	120 pF Capacitor, 0402 Pkg.
L1, L2	560 nH Inductor, 0603 Pkg..
R1, R2	0 Ohm Resistor, 0603 Pkg.
U1	HMC549MS8G(E) Low Noise Amplifier
U2	ETC1-1-13 I:I Balun
PCB ^[2]	109234 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: FR4

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 75 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Evaluation PCB



List of Materials for Evaluation PCB 113184 ^[1]

Item	Description
J1 - J3	BOMAR F Type 75 Ohm Connectors
J4, J5	DC Pin
C1, C2	18 k μ F Capacitor, 0402 Pkg.
C3	150 pF Capacitor, 0402 Pkg.
C4	1,000 pF Capacitor, 0402 Pkg.
C5	390 pF Capacitor, 0603 Pkg.
C6	4.7 μ F Capacitor, Tantalum
C7, C8	120 pF Capacitor, 0402 Pkg.
L1, L2	560 nH Inductor, 0603 Pkg..
U1	HMC549MS8G(E) Low Noise Amplifier
PCB ^[2]	113182 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: FR4

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 75 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.